Features

- Fast read access time 90ns
- Dual voltage range operation
 - Unregulated battery power supply range, 2.7V to 3.6V, or
 - Standard power supply range, $5V \pm 10\%$
- Compatible with JEDEC standard Atmel[®] AT27C010
- Low-power CMOS operation
 - $-20\mu\text{A}$ max standby (less than $1\mu\text{A}$, typical) for $V_{CC}=3.6\text{V}$
 - 29mW max active at 5MHz for $V_{CC} = 3.6V$
- JEDEC standard package
 - 32-lead PLCC
- High-reliability CMOS technology
 - 2,000V ESD protection
 - 200mA latchup immunity
- Rapid programming algorithm 100µs/byte (typical)
- CMOS- and TTL-compatible inputs and outputs
 - JEDEC standard for LVTTL and LVBO
- Integrated product identification code
- Industrial temperature range
- Green (Pb/halide-free) packaging option

1. Description

The Atmel AT27BV010 is a high-performance, low-power, low-voltage 1,048,576-bit, one-time programmable, read-only memory (OTP EPROM) organized as 128K by 8 bits. It requires only one supply in the range of 2.7V to 3.6V in normal read mode operation, making it ideal for fast, portable systems using either regulated or unregulated battery power.

The innovative Atmel design techniques provide fast speeds that rival 5V parts, while keeping the low power consumption of a 3V supply. At $V_{CC}=2.7V$, any byte can be accessed in less than 90ns. With a typical power draw of only 18mW at 5MHz and $V_{CC}=3V$, the AT27BV010 consumes less than one-fifth the power of a standard, 5V EPROM. Standby mode supply current is typically less than 1 μ A at 3V. The AT27BV010 simplifies system design and stretches battery lifetime even further by eliminating the need for power supply regulation.

The AT27BV010 is available in an industry-standard, JEDEC-approved, one-time programmable (OTP) PLCC package. All devices feature two-line control $(\overline{CE}, \overline{OE})$ to give designers the flexibility to prevent bus contention.

The AT27BV010 operating with V_{CC} at 3.0V produces TTL-level outputs that are compatible with standard TTL logic devices operating at $V_{CC} = 5.0$ V. At $V_{CC} = 2.7$ V, the part is compatible with JEDEC-approved, low-voltage battery operation (LVBO) interface specifications. The device is also capable of standard, 5V operation, making it ideally suited for dual supply range systems or card products that are pluggable in both 3V and 5V hosts.

The AT27BV010 has additional features to ensure high quality and efficient production use. The rapid programming algorithm reduces the time required to program the part and guarantees reliable programming. Programming time is typically only 100µs/byte. The integrated product identification code electronically identifies the device and manufacturer.



1Mb (128K x 8)
Unregulated
Battery Voltage,
One-time
Programmable,
Read-only Memory

Atmel AT27BV010



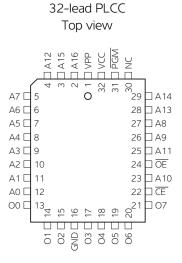




This feature is used by industry-standard programming equipment to select the proper programming algorithms and voltages. The AT27BV010 programs in exactly the same way as a standard, 5V AT27C010, and uses the same programming equipment.

2. Pin configurations

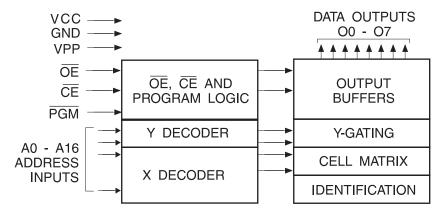
Function
Addresses
Outputs
Chip enable
Output enable
Program strobe
No connect



3. System considerations

Switching between active and standby conditions via the chip enable pin may produce transient voltage excursions. Unless accommodated by the system design, these transients may exceed datasheet limits, resulting in device non-conformance. At a minimum, a $0.1\mu\text{F}$, high-frequency, low inherent inductance, ceramic capacitor should be utilized for each device. This capacitor should be connected between the V_{CC} and ground terminals of the device, as close to the device as possible. Additionally, to stabilize the supply voltage level on printed circuit boards with large EPROM arrays, a $4.7\mu\text{F}$ bulk electrolytic capacitor should be utilized, again connected between the V_{CC} and ground terminals. This capacitor should be positioned as close as possible to the point where the power supply is connected to the array.

Figure 3-1. Block diagram



4. Absolute maximum ratings*

Temperature under bias40°C to +85°C
Storage temperature65°C to +125°C
Voltage on any pin with respect to ground2.0V to +7.0V ⁽¹⁾
Voltage on A9 with respect to ground2.0V to +14.0V ⁽¹⁾
V _{PP} supply voltage with respect to ground2.0V to +14.0V ⁽¹⁾

*NOTICE: Stresses beyond those listed under "Absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these, or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended

periods may affect device reliability.

Note:

1. Minimum voltage is -0.6V DC, which may undershoot to -2.0V for pulses of less than 20ns. Maximum output pin voltage is $V_{CC} + 0.75V$ DC, which may be exceeded if certain precautions are observed (consult application notes), and which may overshoot to +7.0V for pulses of less than 20ns.

5. AC and DC charcteristics

Table 5-1. Operating mode

Mode/Pin	CE	ŌĒ	PGM	Ai	V _{PP}	V _{CC}	Outputs
Read ⁽²⁾	V _{IL}	V _{IL}	X ⁽¹⁾	Ai	X	V _{CC}	D _{OUT}
Output disable ⁽²⁾	X	V _{IH}	X	×	X	V _{CC}	High Z
Standby ⁽²⁾	V _{IH}	X	Х	X	Х	V _{CC}	High Z
Rapid program ⁽³⁾	V _{IL}	V _{IH}	V _{IL}	Ai	V _{PP}	V _{CC}	D _{IN}
PGM verify ⁽³⁾	V _{IL}	V _{IL}	V _{IH}	Ai	V _{PP}	V _{CC}	D _{OUT}
PGM inhibit ⁽³⁾	V _{IH}	X	X	X	V _{PP}	V _{CC}	High Z
Product identification ⁽³⁾⁽⁵⁾	V _{IL}	V _{IL}	X	$A9 = V_{H}^{(4)}$ $A0 = V_{IH} \text{ or } V_{IL}$ $A1 - A16 = V_{IL}$	X	V _{CC}	ldentification code

Note:

- 1. X can be V_{IL} or V_{IH} .
- 2. Read, output disable, and standby modes require 2.7V \leq V_{CC} \leq 3.6V or 4.5V \leq V_{CC} \leq 5.5V.
- 3. Refer to programming characteristics. Programming modes require $V_{CC} = 6.5V$.
- 4. $V_H = 12.0 \pm 0.5 V$.
- 5. Two identifier bytes may be selected. All Ai inputs are held low (V_{\parallel}) except A9, which is set to V_{H} , and A0, which is toggled low (V_{\parallel}) to select the manufacturer's identification byte and high (V_{\parallel}) to select the device code byte.

Table 5-2. DC and AC operating conditions for read operation

	Atmel AT27BV010-90
Industrial operating temperature (case)	-40°C - 85°C
V. savasavani	2.7V to 3.6V
V _{CC} power supply	5V ± 10%





Table 5-3. DC and operating characteristics for read operation

Symbol	Parameter	Condition	Min	Max	Units
$V_{CC} = 2.7V$	to 3.6V				
ILI	Input load current	$V_{IN} = OV \text{ to } V_{CC}$		±1	μA
I _{LO}	Output leakage current	V _{OUT} = 0V to V _{CC}		±5	μA
I _{PP1} (2)	V _{PP} ⁽¹⁾ read/standby current	$V_{PP} = V_{CC}$		10	μA
	V (1) standby surrent	I_{SB1} (CMOS), $\overline{CE} = V_{CC \pm} 0.3V$		20	μA
I _{SB}	V _{CC} ⁽¹⁾ standby current	I_{SB2} (TTL), \overline{CE} = 2.0 to V_{CC} + 0.5V		100	μA
l _{CC}	V _{CC} active current	$f = 5MHz$, $I_{OUT} = 0mA$, $\overline{CE} = V_{IL}$, $V_{CC} = 3.6V$		8	mA
\	la a chi la consulta a c	V _{CC} = 3.0 to 3.6V	-0.6	0.8	V
V_{\parallel}	Input low voltage	V _{CC} = 2.7 to 3.6V	-0.6	0.2 x V _{CC}	V
		V _{CC} = 3.0 to 3.6V	2.0	V _{CC} + 0.5	V
V_{IH}	Input high voltage	V _{CC} = 2.7 to 3.6V	0.7 x V _{CC}	V _{CC} + 0.5	V
		I _{OL} = 2.0mA		0.4	V
V_{OL}	Output low voltage	I _{OL} = 100μA		0.2	V
		I _{OL} = 20μA		0.1	V
		I _{OH} = -2.0mA	2.4		V
V_{OH}	Output high voltage	I _{OH} = -100μA	V _{CC} - 0.2		V
		$I_{OH} = -20\mu A$	V _{CC} - 0.1		V
$V_{CC} = 4.5V$	to 5.5V				
ILI	Input load current	$V_{IN} = OV \text{ to } V_{CC}$		±1	μA
I _{LO}	Output leakage current	$V_{OUT} = 0V \text{ to } V_{CC}$		±5	μA
I _{PP1} (2)	V _{PP} ⁽¹⁾ read/standby current	$V_{pp} = V_{CC}$		10	μA
1	V (1) standby surrent	I_{SB1} (CMOS), $\overline{CE} = V_{CC} \pm 0.3V$		100	μA
I _{SB}	V _{CC} ⁽¹⁾ standby current	I_{SB2} (TTL), \overline{CE} = 2.0 to V_{CC} + 0.5V		1	mA
I _{CC}	V _{CC} active current	$f = 5MHz$, $I_{OUT} = 0mA$, $\overline{CE} = V_{IL}$		25	mA
V _{IL}	Input low voltage		-0.6	0.8	V
V _{IH}	Input high voltage		2.0	V _{CC} + 0.5	V
V _{OL}	Output low voltage	I _{OL} = 2.1mA		0.4	V
V _{OH}	Output high voltage	I _{OH} = -400μA	2.4		V

Notes: 1. V_{CC} must be applied simultaneously with or before V_{PP} , and removed simultaneously with or after V_{PP} .

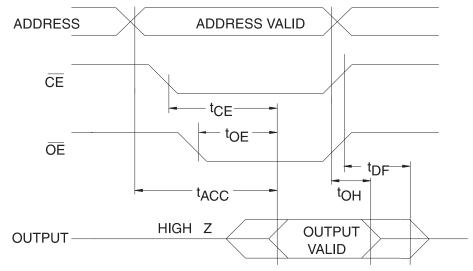
^{2.} V_{PP} may be connected directly to V_{CC} , except during programming. The supply current would then be the sum of I_{CC} and I_{PP} .

Table 5-4. AC characteristics for read operation

 V_{CC} = 2.7V to 3.6V and 4.5V to 5.5V

			-9		
Symbol	Parameter	Condition	Min	Max	Units
t _{ACC} (3)	Address to output delay	$\overline{CE} = \overline{OE} = V_{IL}$		90	ns
t _{CE} ⁽²⁾	CE to output delay	$\overline{OE} = V_{IL}$		90	ns
t _{OE} ⁽²⁾⁽³⁾	OE to output delay	CE = V _{IL}		50	ns
t _{DF} ⁽⁴⁾⁽⁵⁾	OE or CE high to output float, whichever occurred first			40	ns
t _{OH}	Output hold from address, $\overline{\text{CE}}$ or $\overline{\text{OE}}$, whichever occurred first		0		ns

Figure 5-1. AC waveforms for read operation⁽¹⁾



Notes: 1. Timing measurement references are 0.8V and 2.0V. Input AC drive levels are 0.45V and 2.4V, unless otherwise specified.

- 2. \overline{OE} may be delayed up to t_{CE} - t_{OE} after the falling edge of \overline{CE} without impact on t_{CE} .
- 3. \overline{OE} may be delayed up to t_{ACC} - t_{OE} after the address is valid without impact on t_{ACC} -
- 4. This parameter is only sampled, and is not 100% tested.
- 5. Output float is defined as the point when data is no longer driven.

Figure 5-2. Input test waveform and measurement level

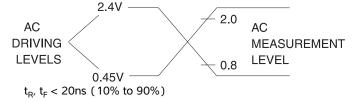






Figure 5-3. Output test load

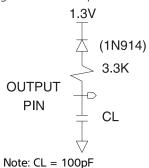


Table 5-5. Pin capacitance

 $f = 1MHz, T = 25°C^{(1)}$

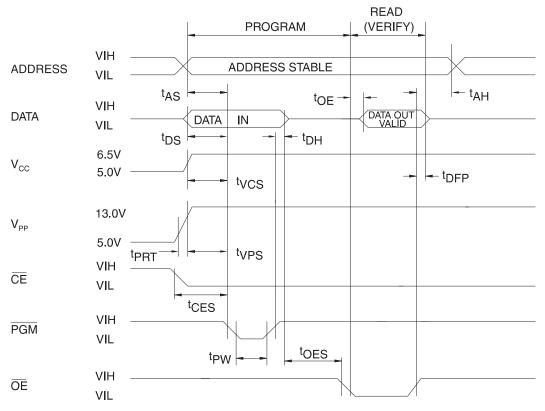
including jig capacitance.

 Symbol
 Typ
 Max
 Units
 Conditions

 C_{IN} 4
 8
 pF
 $V_{IN} = 0V$
 C_{OUT} 8
 12
 pF
 $V_{OUT} = 0V$

Note: 1. Typical values for nominal supply voltage. This parameter is only sampled, and is not 100% tested.

Figure 5-4. Programming waveforms⁽¹⁾



Notes: 1. The input timing reference is 0.8V for $V_{\rm IL}$ and 2.0V for $V_{\rm IH}$.

- 2. t_{OE} and t_{DFP} are characteristics of the device, but must be accommodated by the programmer.
- 3. When programming the Atmel AT27BV010, a $0.1\mu F$ capacitor is required across V_{pp} and ground to suppress spurious voltage transients.

Table 5-6. DC programming charcteristics

 $T_A = 25 \pm 5$ °C, $V_{CC} = 6.5 \pm 0.25$ V, $V_{PP} = 13.0 \pm 0.25$ V

			Lin		
Symbol	Parameter	Test conditions	Min	Max	Units
I _{LI}	Input load current	$V_{IN} = V_{IL}, V_{IH}$		±10	μΑ
V _{IL}	Input low level		-0.6	0.8	V
V _{IH}	Input high level		2.0	V _{CC} + 1	V
V _{OL}	Output low voltage	I _{OL} = 2.1mA		0.4	V
V _{OH}	Output high voltage	Ι _{ΟΗ} = -400μΑ	2.4		V
I _{CC2}	V _{CC} supply current (program and verify)			40	mA
I _{PP2}	V _{pp} supply current	$\overline{CE} = \overline{PGM} = V_{IL}$		20	mA
V _{ID}	A9 product identification voltage		11.5	12.5	V

Table 5-7. AC programming charcteristics

 $T_A = 25 \pm 5$ °C, $V_{CC} = 6.5 \pm 0.25$ V, $V_{PP} = 13.0 \pm 0.2$ V

				nits	
Symbol	Parameter	Test conditions ⁽¹⁾	Min	Max	Units
t _{AS}	Address setup time		2		μs
t _{CES}	CE setup time	Input rise and fall times:	2		μs
t _{OES}	OE setup time	(10% to 90%) 20ns	2		μs
t _{DS}	Data setup time		2		μs
t _{AH}	Address hold time	Input pulse levels: 0.45V to 2.4V	0		μs
t _{DH}	Data hold time	0.43 V to 2.4 V	2		μs
t _{DFP}	OE high to output float delay ⁽²⁾	Input timing reference level:	0	130	ns
t _{VPS}	V _{PP} setup time	0.8V to 2.0V	2		μs
t _{VCS}	V _{CC} setup time	Output timing reference level:	2		μs
t _{PW}	PGM program pulse width ⁽³⁾	0.8V to 2.0V	95	105	μs
t _{OE}	Data valid from OE			150	ns
t _{PRT}	V _{PP} pulse rise time during programming		50		ns

Notes:

- 1. V_{CC} must be applied simultaneously with or before V_{PP} and removed simultaneously with or after V_{PP} .
- 2. This parameter is only sampled, and is not 100% tested. Output float is defined as the point where data is no longer driven. See timing diagram.
- 3. Program pulse width tolerance is $100\mu \sec \pm 5\%$.

Table 5-8. The Atmel AT27BV010 integrated product identification code⁽¹⁾

		Pins					Hex			
Codes	A0	07	O6	O5	04	О3	02	01	00	Data
Manufacturer	0	0	0	0	1	1	1	1	0	1E
Device type	1	0	0	0	0	0	1	0	1	05

Note: 1. The Atmel AT27BV010 has the same product identification code as the Atmel AT27C010. Both are programming compatible.

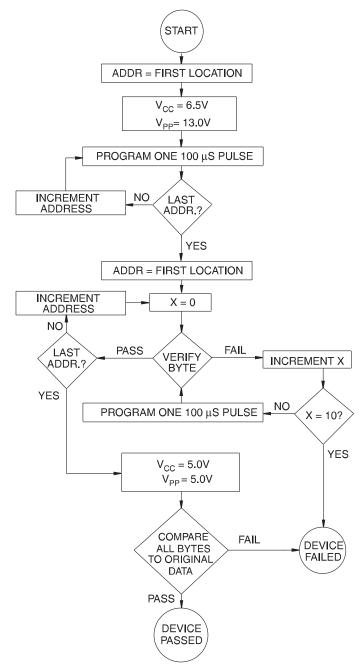




6. Rapid programming algorithm

A 100 μ s \overline{PGM} pulse width is used to program. The address is set to the first location. V_{CC} is raised to 6.5V and V_{PP} is raised to 13.0V. Each address is first programmed with one 100 μ s \overline{PGM} pulse without verification. Then a verification/reprogramming loop is executed for each address. In the event a byte fails to pass verification, up to 10 successive 100 μ s pulses are applied with a verification after each pulse. If the byte fails to verify after 10 pulses have been applied, the part is considered failed. After the byte verifies properly, the next address is selected until all have been checked. V_{PP} is then lowered to 5.0V and V_{CC} to 5.0V. All bytes are read again and compared with the original data to determine if the device passes or fails.

Figure 6-1. Rapid programming algorithm



7. Ordering Information

Green package (Pb/hailde-free)

t _{ACC}	I_{CC} (mA) $V_{CC} = 3.6V$					
(ns)	Active	Standby	Atmel ordering code	Lead finish	Package	Operation range
90	8	0.02	AT27BV010-90JU	Matte tin	32J	Industrial (-40°C to 85°C)

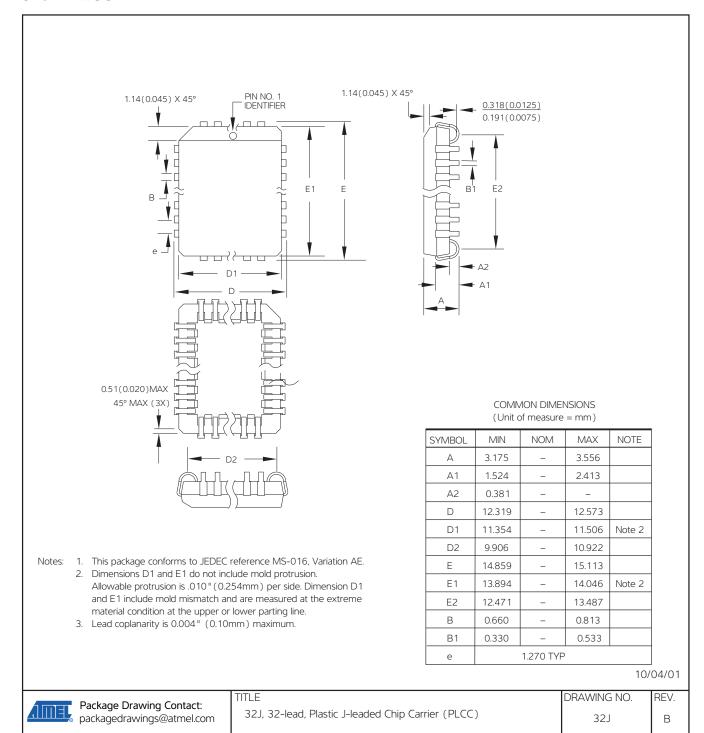
Package types					
32J 32-lead, plastic, J-leaded chip carrier (PLCC)					





8. Packaging information

32J – PLCC



9. Revision history

Doc. rev.	Date	Comments
03441	04/2011	Remove TSOP and VSOP packages Add lead finish to ordering information
0344H	12/2007	





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